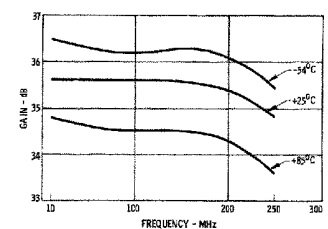




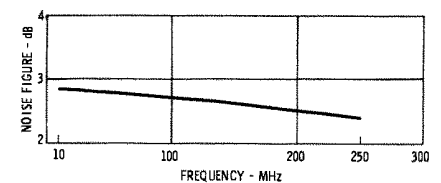
Typical Performance @ 25°C

| Characteristics | Typical | Guaranteed | |
|----------------------------------|---------|------------|---------------|
| | | 0° to 50°C | -54° to +85°C |
| Frequency | | | |
| Small Signal Gain (min.) | | | |
| Gain Flatness (max.) | | | |
| Reverse Isolation | | | |
| Noise Figure (max.) | | | |
| Power Output @ 1 dB comp. (min.) | | | |
| IP3 | | | |
| IP2 | | | |
| Second Order Harmonic IP | | | |
| VSWR Input / Output (max.) | | | |
| DC Current @ | | | |

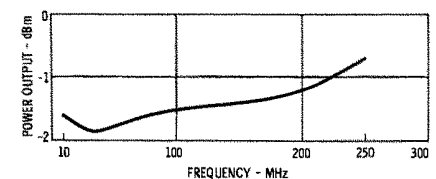
Gain



Noise Figure

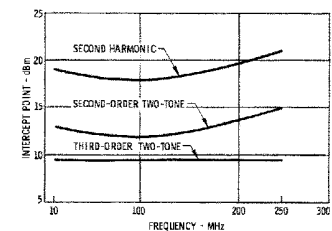


Power Output *

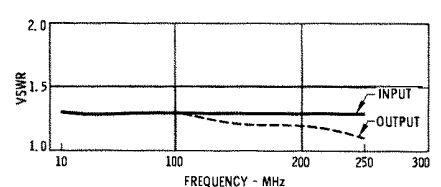


*** at 1 dB Gain Compression**

Intercept Point



VSWR



Absolute Maximum Ratings

- Storage Temperature
- Max. Case Temperature
- Max. DC Voltage
- Max. Continuous RF Input Power
- Max. Short Term RF Input Power (1 minute max.)
- Max. Peak Power (3 μsec max.)
- “S” Series Burn-in Temperature (Case)

Thermal Data: $V_{cc} =$

- Thermal Resistance θ_{jc}
- Transistor Power Dissipation P_d
- Junction Temperature Rise Above Case T_{jc}

Outline Drawings

| Package Figure Model | TO-8 | Surface Mount | SMA Connectorized |
|----------------------|------|---------------|-------------------|
| | | | |